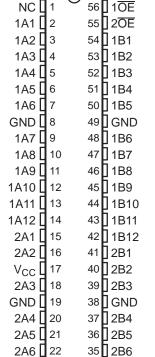
www.ti.com

24-BIT FET BUS SWITCH 2.5-V/3.3-V LOW-VOLTAGE BUS SWITCH WITH 5-V TOLERANT LEVEL SHIFTER

Check for Samples: SN74CB3T16211

FEATURES

- Member of the Texas Instruments Widebus™ Family
- **Output Voltage Translation Tracks V_{CC}**
- **Supports Mixed-Mode Signal Operation on** All Data I/O Ports
 - 5-V Input Down to 3.3-V Output Level Shift With 3.3-V V_{CC}
 - 5-V/3.3-V Input Down to 2.5-V Output Level Shift With 2.5-V V_{CC}
- 5-V Tolerant I/Os With Device Powered Up or Powered Down
- **Bidirectional Data Flow With Near-Zero Propagation Delay**
- Low ON-State Resistance (ron) Characteristics $(r_{on} = 5 \Omega Typ)$
- Low Input/Output Capacitance Minimizes Loading ($C_{io(OFF)} = 5 pF Typ$)
- **Data and Control Inputs Provide Undershoot Clamp Diodes**
- **Low Power Consumption** $(I_{CC} = 70 \mu A Max)$
- V_{CC} Operating Range From 2.3 V to 3.6 V
- Data I/Os Support 0- to 5-V Signaling Levels (0.8 V, 1.2 V, 1.5 V, 1.8 V, 2.5 V, 3.3 V, 5 V)
- Control Inputs Can Be Driven by TTL or 5-V/3.3-V CMOS Outputs
- I_{off} Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 250 mA Per **JESD 17**
- **ESD Performance Tested Per JESD 22**
 - 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)
- **Supports Digital Applications: Level** Translation, PCI Interface, Bus Isolation
- Ideal for Low-Power Portable Equipment



DGG, DGV, OR DL PACKAGE

(TOP VIEW)

NC - No internal connection

28

34 2B7

33 2B8

32 1 2B9

31 **□** 2B10

30 2B11

29 1 2B12

2A7 1 23

2A8 **∏** 24

2A9 **1**25

2A10 **∏** 26

2A11 1 27

2A12 🛮

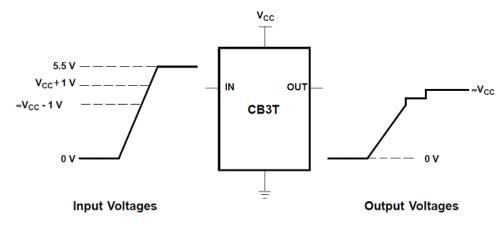
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. Widebus is a trademark of Texas Instruments.



DESCRIPTION/ORDERING INFORMATION

The SN74CB3T16211 is a high-speed TTL-compatible FET bus switch with low ON-state resistance (r_{on}), allowing for minimal propagation delay. The device fully supports mixed-mode signal operation on all data I/O ports by providing voltage translation that tracks V_{CC} . The SN74CB3T16211 supports systems using 5-V TTL, 3.3-V LVTTL, and 2.5-V CMOS switching standards, as well as user-defined switching levels (see Figure 1).

DESCRIPTION/ORDERING INFORMATION (CONTINUED)



If the input high voltage (V_{IH}) level is greater than or equal to V_{CC} + 1V, and less than or equal to 5.5 V, the output high voltage (V_{OH}) level will be equal to approximately the V_{CC} voltage level.

Figure 1. Typical DC Voltage-Translation Characteristics

The I/O port of this device has a pullup current source that maintains the output voltage at V_{CC} when the device is ON, and the input is greater than or equal to $V_{CC}-1$. Because of the pullup current source, the output voltage level may be less than V_{CC} when the operating frequency is low and the I/O port is connected to a pulldown resistor. In order to maintain the output voltage at V_{CC} , a pullup resistor must be connected to V_{CC} instead of a pulldown resistor to ground.

The SN74CB3T16211 is organized as two 12-bit bus switches with separate output-enable $(1\overline{OE}, 2\overline{OE})$ inputs. It can be used as two 12-bit bus switches or as one 24-bit bus switch. When \overline{OE} is low, the associated 12-bit bus switch is ON, and the A port is connected to the B port, allowing bidirectional data flow between ports. When \overline{OE} is high, the associated 12-bit bus switch is OFF, and a high-impedance state exists between the A and B ports.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} feature ensures that damaging current will not backflow through the device when it is powered down. The device has isolation during power off.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

PACKAGE⁽¹⁾ ORDERABLE PART NUMBER TOP-SIDE MARKING T_A Tube SN74CB3T16211DL SSOP - DL CB3T16211 Tape and reel SN74CB3T16211DLR Tube SN74CB3T16211DGG TSSOP - DGG CB3T16211 -40°C to 85°C Tape and reel SN74CB3T16211DGGR TVSOP - DGV Tape and reel SN74CB3T16211DGVR KR211 VFBGA - GQL (Pb-free) Tape and reel SN74CB3T16211GQLR KR211 VFBGA - ZQL (Pb-free) Tape and reel SN74CB3T16211ZQLR KR211

Table 1. ORDERING INFORMATION

 Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



GQL OR ZQL PACKAGE (TOP VIEW)

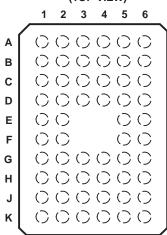


Table 2. TERMINAL ASSIGNMENTS

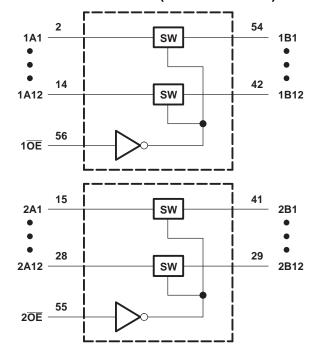
	1	2	3	4	5	6
Α	1A2	1A1	NC ⁽¹⁾	1 OE	2 OE	1B1
В	1A5	1A4	1A3	1B2	1B3	1B4
С	1A7	GND	1A6	1B5	GND	1B6
D	1A10	1A8	1A9	1B8	1B7	1B9
E	1A12	1A11			1B10	1B11
F	2A1	2A2			2B1	1B12
G	V _{CC}	GND	2A3	2B3	GND	2B2
Н	2A4	2A5	2A6	2B6	2B5	2B4
J	2A7	2A8	2A9	2B9	2B8	2B7
K	2A10	2A11	2A12	2B12	2B11	2B10

(1) NC - No internal connection

Table 3. FUNCTION TABLE (EACH 12-BIT BUS SWITCH)

INPUT OE	INPUT/OUTPUT A	FUNCTION
L	В	A port = B port
Н	Z	Disconnect

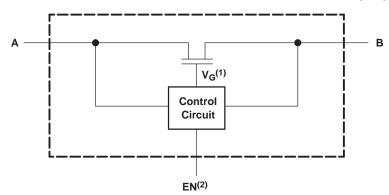
LOGIC DIAGRAM (POSITIVE LOGIC)



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SIMPLIFIED SCHEMATIC, EACH FET SWITCH (SW)



- (1) Gate voltage (V_G) is approximately equal to V_{CC} + V_T when the switch is ON and V_I > V_{CC} + V_T.
- (2) Internal enable signal applied to the switch

Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range ⁽²⁾		-0.5	7	V
V _{IN}	Control input voltage range (2) (3)		-0.5	7	V
V _{I/O}	Switch I/O voltage range ^{(2) (3) (4)}		-0.5	7	V
I _{IK}	Control input clamp current	V _{IN} < 0		-50	mA
I _{I/OK}	I/O port clamp current	V _{I/O} < 0		-50	mA
I _{I/O}	ON-state switch current ⁽⁵⁾		±128	mA	
	Continuous current through V _{CC} or GND		±100	mA	
		DGG package		64	
0	Package thermal impedance (6)	DGV package		48	°C/W
ОЈА	Package thermal impedance ***	DL package		56	C/VV
θ _{JA} i		GQL/ZQL package		42	
T _{stg}	Storage temperature range		-65	150	°C

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltages are with respect to ground, unless otherwise specified.
- (3) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- (4) V_I and V_O are used to denote specific conditions for V_{I/O}.
- (5) I_1 and I_0 are used to denote specific conditions for $I_{1/0}$.
- (6) The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Conditions⁽¹⁾

			MIN	MAX	UNIT
V_{CC}	Supply voltage		2.3	3.6	V
\/	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		1.7	5.5	V
V _{IH}	High-level control input voltage	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2	5.5	V
.,	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0	0.7	
V _{IL}	Low-level control input voltage	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	0	0.8	V
V _{I/O}	Data input/output voltage		0	5.5	V
T _A	Operating free-air temperature		-40	85	°C

 All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

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Electrical Characteristics(1)

over recommended operating free-air temperature range (unless otherwise noted)

P/	ARAMETER	TEST CONDITI	ONS	MIN	TYP ⁽²⁾	MAX	UNIT		
V _{IK}		V _{CC} = 3 V, I _I = -18 mA			-1.2	V			
V _{OH}		See Figure 3 and Figure 4							
I _{IN}	Control inputs	$V_{CC} = 3.6 \text{ V}, V_{IN} = 3.6 \text{ V to } 5.5 \text{ V or GN}$	D			±10	μA		
			$V_I = V_{CC} - 0.7 \text{ V to } 5.5 \text{ V}$			±20			
I _I		$V_{CC} = 3.6 \text{ V}$, Switch ON, $V_{IN} = V_{CC}$ or GND	$V_{I} = 0.7 \text{ V to } V_{CC} - 0.7 \text{ V}$			-40	μΑ		
		VIN = VCC or SIVE	$V_{I} = 0 \text{ to } 0.7 \text{ V}$			±5			
I _{OZ} (3)		V_{CC} = 3.6 V, V_{O} = 0 to 5.5 V, V_{I} = 0, Switch OFF, V_{IN} = V_{CC} or GND			±10	μΑ			
I _{off}		$V_{CC} = 0$, $V_{O} = 0$ to 5.5 V, $V_{I} = 0$				10	μA		
I _{CC}		$V_{CC} = 3.6 \text{ V}, I_{I/O} = 0,$	$V_I = V_{CC}$ or GND			70			
		Switch ON or OFF, $V_{IN} = V_{CC}$ or GND	V _I = 5.5 V			70	μA		
$\Delta I_{CC}^{~(4)}$	Control inputs	V_{CC} = 3 V to 3.6 V, One input at V_{CC} – 0 Other inputs at V_{CC} or GND	0.6 V,			300	μΑ		
C _{in}	Control inputs	$V_{CC} = 3.3 \text{ V}, V_{IN} = V_{CC} \text{ or GND}$			4		pF		
C _{io(OFF)}		V_{CC} = 3.3 V, $V_{I/O}$ = 5.5 V, 3.3 V, or GNI Switch OFF, V_{IN} = V_{CC} or GND	D,		5		pF		
0		V _{CC} = 3.3 V, Switch ON,	V _{I/O} = 5.5 V or 3.3 V		5				
$C_{io(ON)}$		$V_{IN} = V_{CC}$ or GND	$V_{I/O} = GND$		13		pF		
		$V_{CC} = 2.3 \text{ V}$, TYP at $V_{CC} = 2.5 \text{ V}$,	I _O = 24 mA		5	9.5			
" (5)		$V_1 = 0$	I _O = 16 mA		5	9.5	Ω		
r _{on} ⁽⁵⁾		V 2V V 0	I _O = 64 mA		5	8.5			
		$V_{CC} = 3 \text{ V}, V_I = 0$	I _O = 32 mA		5	8.5			

- V_{IN} and I_{IN} refer to control inputs. V_{I} , V_{O} , I_{I} , and I_{O} refer to data pins. All typical values are at $V_{CC}=3.3~V$ (unless otherwise noted), $T_{A}=25^{\circ}C$. For I/O ports, the parameter I_{OZ} includes the input leakage current. This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V_{CC} or GND.
- Measured by the voltage drop between A and B terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 2)

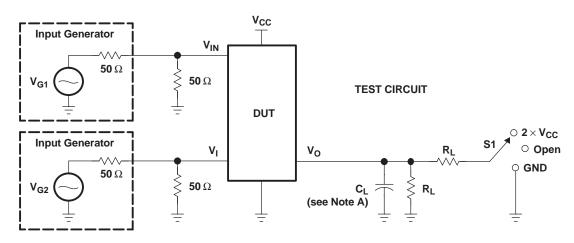
PARAMETER	FROM (INPUT)	TO	V _{CC} = ± 0.2	2.5 V 2 V	V _{CC} = 3 ± 0.3	UNIT	
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	
t _{pd} ⁽¹⁾	A or B	B or A		0.15		0.25	ns
t _{en}	ŌĒ	A or B	1	12	1	10	ns
t _{dis}	ŌĒ	A or B	1	7.5	1	8.5	ns

The propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

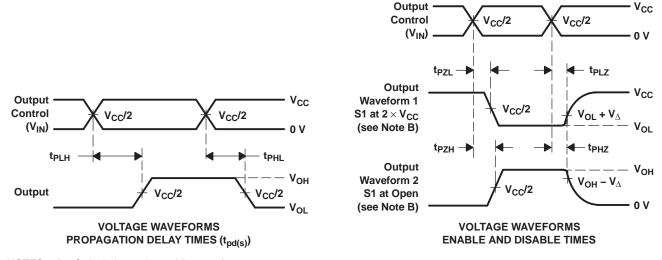
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PARAMETER MEASUREMENT INFORMATION



TEST	V _{CC}	S1	R _L	VI	CL	\mathbf{V}_{Δ}
t _{pd(s)}	$\begin{array}{c} \textbf{2.5 V} \pm \textbf{0.2 V} \\ \textbf{3.3 V} \pm \textbf{0.3 V} \end{array}$			3.6 V or GND 5.5 V or GND		
t _{PLZ} /t _{PZL}	$\begin{array}{c} \textbf{2.5 V} \pm \textbf{0.2 V} \\ \textbf{3.3 V} \pm \textbf{0.3 V} \end{array}$		500 Ω 500 Ω	GND GND	30 pF 50 pF	0.15 V 0.3 V
t _{PHZ} /t _{PZH}	$\begin{array}{c} \textbf{2.5 V} \pm \textbf{0.2 V} \\ \textbf{3.3 V} \pm \textbf{0.3 V} \end{array}$	Open Open	500 Ω 500 Ω	3.6 V 5.5 V	30 pF 50 pF	0.15 V 0.3 V



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50~\Omega$, $t_f \leq$ 2.5 ns, $t_f \leq$ 2.5 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
- F. t_{PZL} and t_{PZH} are the same as t_{en}.
- G. t_{PLH} and t_{PHL} are the same as t_{pd(s)}. The t_{pd} propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).
- H. All parameters and waveforms are not applicable to all devices.

Figure 2. Test Circuit and Voltage Waveforms



TYPICAL CHARACTERISTICS

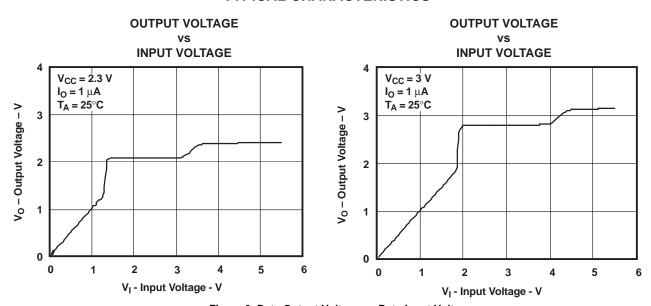
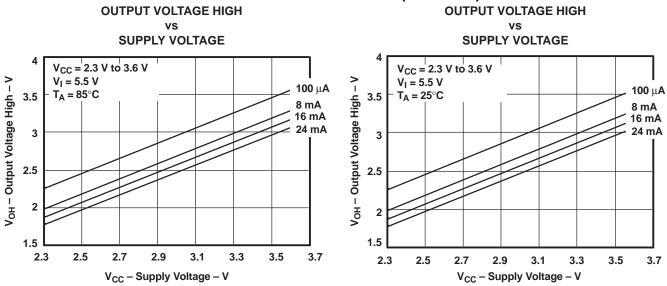


Figure 3. Data Output Voltage vs Data Input Voltage



TYPICAL CHARACTERISTICS (continued)



OUTPUT VOLTAGE HIGH

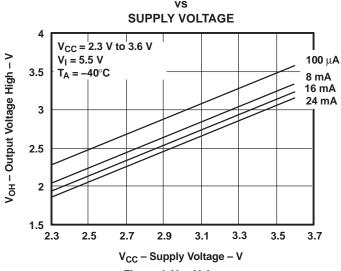


Figure 4. V_{OH} Values



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REVISION HISTORY

CI	anges from Revision B (January 2006) to Revision C Page				
•	Updated graphic and note in figure 1.	2	2		





10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
74CB3T16211DGGRE4	ACTIVE	TSSOP	DGG	56	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CB3T16211	Samples
SN74CB3T16211DGGR	ACTIVE	TSSOP	DGG	56	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CB3T16211	Samples
SN74CB3T16211DGVR	ACTIVE	TVSOP	DGV	56	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	KR211	Samples
SN74CB3T16211DL	ACTIVE	SSOP	DL	56	20	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CB3T16211	Samples
SN74CB3T16211DLR	ACTIVE	SSOP	DL	56	1000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CB3T16211	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



PACKAGE OPTION ADDENDUM

10-Dec-2020

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PACKAGE MATERIALS INFORMATION

www.ti.com 7-Nov-2019

TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

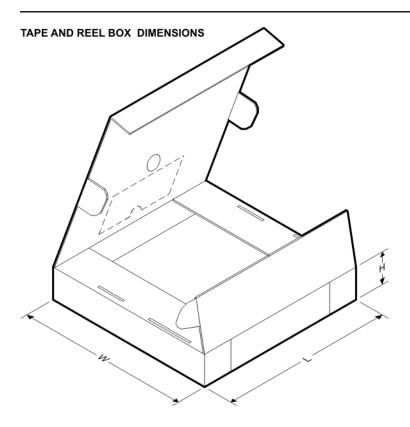
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74CB3T16211DLR	SSOP	DL	56	1000	330.0	32.4	11.35	18.67	3.1	16.0	32.0	Q1

www.ti.com 7-Nov-2019



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74CB3T16211DLR	SSOP	DL	56	1000	367.0	367.0	55.0

DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



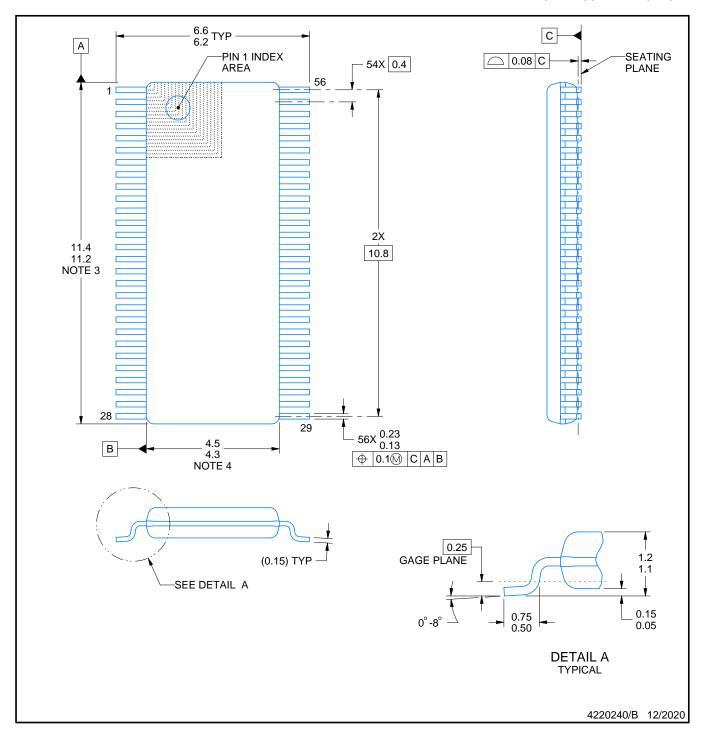
NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194





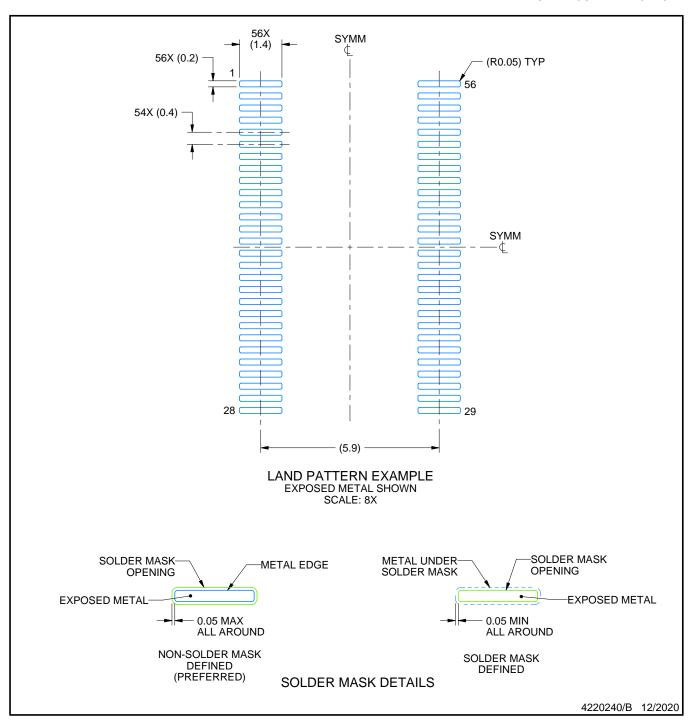
NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-194.



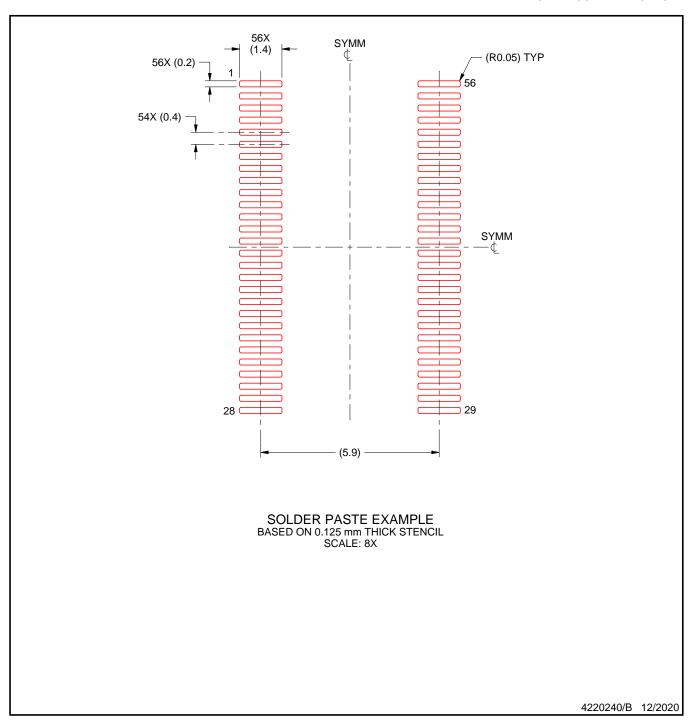


NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



DL (R-PDSO-G56)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

PowerPAD is a trademark of Texas Instruments.







NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
 4. Reference JEDEC registration MO-153.





NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



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